November 2013

FJV3102R NPN Epitaxial Silicon Transistor with Bias Resistor

Description

Features

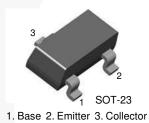
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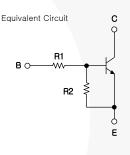
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- 100 mA Output Current Capability
- Built-in Bias Resistor ($R_1 = 10 \text{ k}\Omega$, $R_2 = 10 \text{ k}\Omega$)

Application

- · Switching, Interface, and Driver Circuits
- Inverters
- Digital Applications in Industrial Segments





Transistors with built-in resistors can be excellent

space- and cost-saving solutions by reducing compo-

nent count and simplifying circuit design.

Ordering Information

Part Number	Top Mark	Package	Packing Method
FJV3102RMTF	R22	SOT-23 3L	Tape and Reel

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	50	V
V _{CEO}	Collector-Emitter Voltage	50	V
V _{EBO}	Emitter-Base Voltage	10	V
۱ _C	Collector Current	100	mA
ТJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to 150	°C

Thermal Characteristics⁽¹⁾

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Value	Unit
D	Power Dissipation	200	mW
P _D	Derate Above T _A = 25°C	1.60	mW/°C
R _{0JA}	Thermal Resistance, Junction to Ambient	625	°C/W

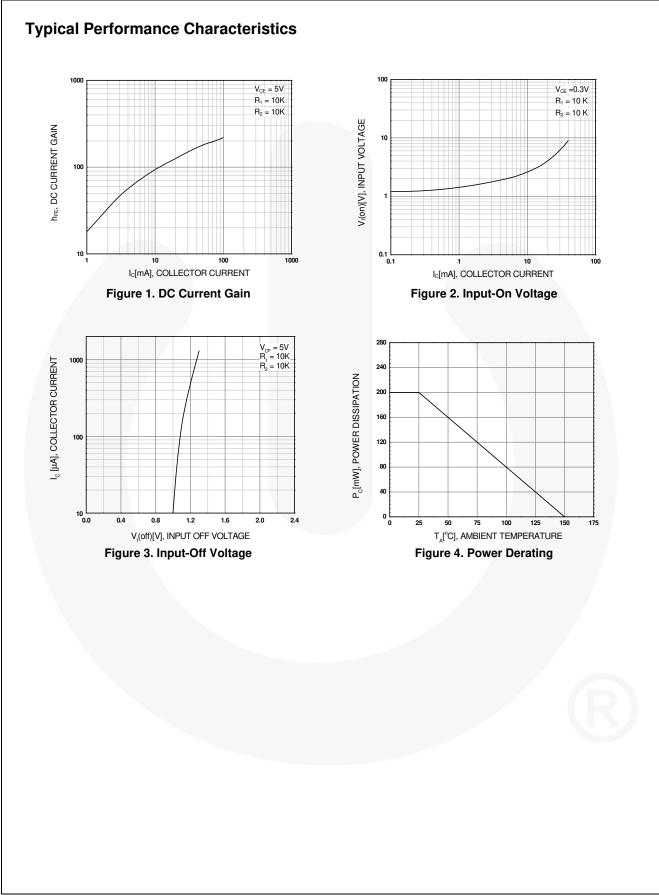
Note:

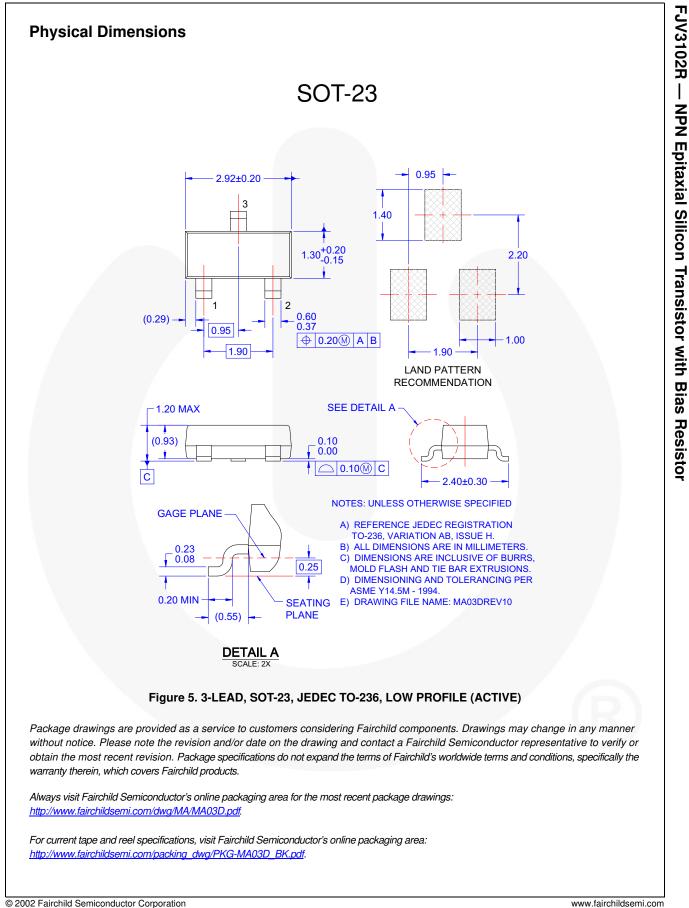
1. FR-4 76 x 114 x 0.6T mm³ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C} = 10 \ \mu A, \ I_{E} = 0$	50			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm B} = 0$	50			V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 40 \text{ V}, I_{E} = 0$			0.1	μA
h _{FE}	DC Current Gain	$V_{CE} = 5 V, I_{C} = 5 mA$	30			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.5 \text{ mA}$			0.3	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$		250		MHz
C _{ob}	Output Capacitance	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0,$ f = 1.0 MHz		3.7		pF
V _I (off)	Input-Off Voltage	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$			0.5	V
V _l (on)	Input-On Voltage	$V_{CE} = 0.3 \text{ V}, I_{C} = 10 \text{ mA}$	3			V
R ₁	Input Resistor		7	10	13	kΩ
R_1/R_2	Resistor Ratio		0.9	1.0	1.1	





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FJV3102R Rev. 1.1.2

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